## General Purpose Transistor Multicomp PRO





#### **Pin Configuration**

- 1. Emitter
- 2. Base
- 3. Collector

#### Features:

- PNP Silicon Planar RF Transistor
- · Small Signal General Purpose Amplifier, Transistor

#### **Absolute Maximum Ratings:**

 $(T_a = 25^{\circ}C \text{ unless otherwise specified})$ 

Characteristic	Symbol	Value	Unit
Collector Base Voltage	V <sub>CBO</sub>	80	
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	
Collector Current	I <sub>CM</sub>	1	А
Power Dissipation at T <sub>a</sub> = 25°C Derate above 25°C	D	800 4.6	mW mW/°C
Power Dissipation at T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	4 22.85	W mW/°C
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	-65 to +200	°C

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#### **Electrical Characteristics:**

 $(T_a = +25^{\circ}C \text{ unless otherwise specified})$ 

Parameter	Symbol	Test Condition	Min.	Max.	Unit
Collector Emitter Breakdown Voltage	BV <sub>CEO</sub> *	$I_{\rm C} = 10  \text{mA}, I_{\rm B} = 0$	80	-	V
Collector Base Breakdown Voltage	BV <sub>CBO</sub>	$I_{C} = 10 \mu A, I_{E} = 0$	60		
Emitter Base Breakdown Voltage	BV <sub>EBO</sub>	$I_{E} = 10 \mu A, I_{C} = 0$	5		
Collector Leakage Current	I <sub>CBO</sub>	$V_{CB} = 60V, I_{E} = 0$		50	nA
		V <sub>CB</sub> = 60V, T <sub>A</sub> = 150°C	-		μA
Emitter Leakage Current	I <sub>EBO</sub>	$V_{EB} = 5V$ , $I_C = 0$		10	μΑ
Collector Emitter Saturation Voltage	V <sub>CE (Sat)</sub> *	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA		0.15	V
		I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	-	0.5	
Base Emitter Saturation Voltage	V <sub>BE(Sat)</sub> *	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA		0.9	V
Base Emitter On Voltage	V <sub>BE(on)</sub> *	$I_{\rm C}$ = 500mA, $V_{\rm CE}$ = 0.5V		1.1	1
DC Current Gain	h <sub>FE</sub> *	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V	75		
		I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V	100	200	
		$I_C = 100 \text{mA}, V_{CE} = 5 \text{V}, T_a = -55 ^{\circ} \text{C}$	40	300	-
		I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V	25		

#### **Small Signal Characteristics**

Transition Frequency	f <sub>T</sub>	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V, f = 100MHz	150	500	MHz
Output Capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		20	۲
Input Capacitance	C <sub>ib</sub>	$V_{BE} = 0.5V, I_{C} = 0, f = 1MHz$		110	pF
Turn on Time	4	I <sub>C</sub> = 500mA, I <sub>B1</sub> = 50mA	-	100	
Storage Time	<sup>L</sup> on	I <sub>C</sub> = 500mA, I <sub>B1</sub> = I <sub>B2</sub> = 50mA		350	ns
Fall Time	t <sub>f</sub>	I <sub>C</sub> = 500mA, I <sub>B1</sub> = I <sub>B2</sub> = 50mA		50	

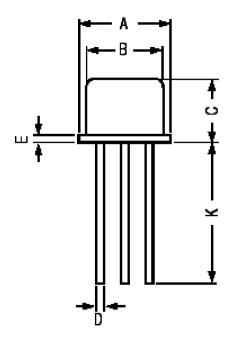
<sup>\*</sup>Pulse Test: Pulse Width ≤300µs, Duty Cycle ≤2%



### General Purpose Transistor Multicomp PRO

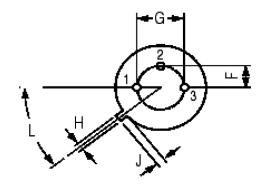


#### TO-39 Metal Can Package



Dim.	Min.	Max.
Α	8.5	9.39
В	7.74	8.5
С	6.09	6.6
D	0.4	0.53
Е	-	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
K	12.7	-
Ĺ	42°	48°

Dimensions: Millimetres



#### **Pin Configuration**

- 1. Emitter
- 3. Collector

#### **Part Number Table**

Description	Part Number		
Transistor, PNP, TO-39	2N4033		

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